

Fig.2

FILM NAME	MATERIALS	CONDUCTIVE TYPE	DOPANT	CARRIER CONCENTRATION (cm ⁻³)	FILM THICKNESS (nm)
EMITTER FILM 6	InP	n	Si	4~20×10 ¹⁸	250
BASE FILM 5	InGaAs	p ⁺	Zn	4×10 ¹⁹	50
COLLECTOR FILM 4	InGaAs	n	Si	5×10 ¹⁶	500
SUBCOLLECTOR FILM 3	InGaAs	n ⁺	Si	1×10 ¹⁹	300

Fig.3

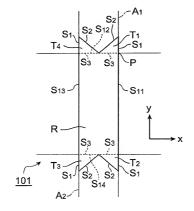


Fig.4

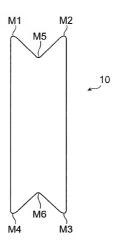
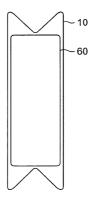


Fig.5



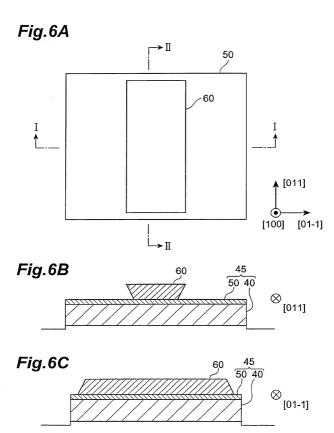


Fig.7A

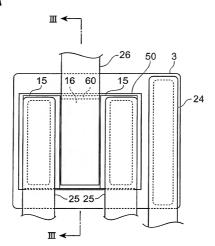
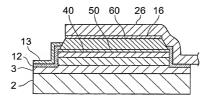


Fig.7B



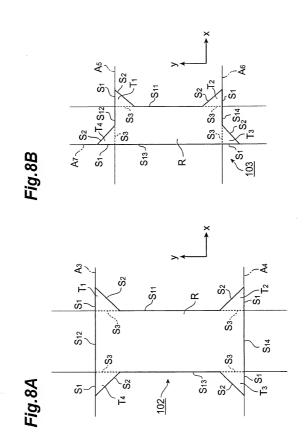
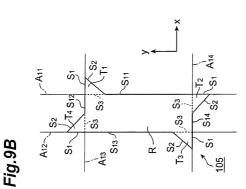


Fig.9A



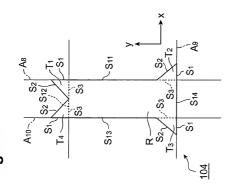


Fig.10

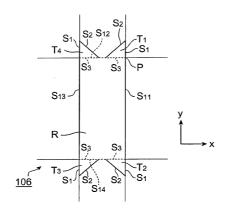
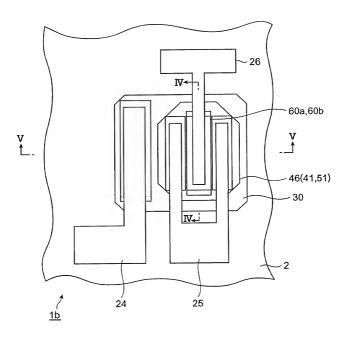
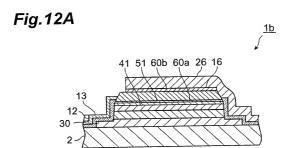


Fig.11





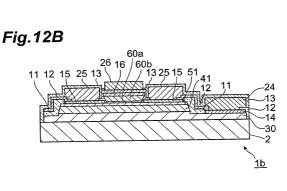


Fig.13A

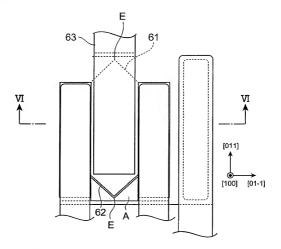


Fig.13B

